

Identification of nucleation parameter for cellular automaton model of dynamic recrystallization

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Received 19 December 2008; accepted 26 May 2009

Abstract: The accuracy of nucleation parameter is a critical factor in the simulation of microstructural evolution during dynamic recrystallization (DRX). Based on the flow stress curve under hot deformation conditions, a new approach is proposed to identify the nucleation parameter during DRX. In this approach, a cellular automaton (CA) model is applied to quantitatively simulate the microstructural evolution and flow stress during hot deformation; and adaptive response surface method (ARSM) is applied as optimization model to provide input parameters to CA model and evaluate the outputs of the latter. By taking an oxygen-free high-conductivity (OFHC) copper as an example, the good agreement between the simulation results and the experimental observations demonstrates the availability of the proposed method.

Key words: dynamic recrystallization; cellular automaton method; response surface method; nucleation rate; parameter identification

1 Introduction

Dynamic recrystallization (DRX) is an important metallurgical phenomenon during high temperature plastic deformation, which is able to change the microstructure of metallic materials, and influence their mechanical properties. Although the traditional model of DRX, i.e. the phenomenological or semi-empirical model based on the experimentation, can build the relationship between grain sizes and deformation parameters, it is not able to reveal the complex physical mechanism during hot working[1]. In recent years, a Monte Carlo (MC) method has been used to dynamically simulate the nucleation and the grain growth during DRX[2–5]. However, its application is limited due to the deficiency that the time step used in MC simulation is difficult to map to real time. Since the Cellular Automaton (CA) method was introduced to DRX by GOETZ and SEETHARAMAN[6], it has been successfully applied to simulate the microstructural evolution of various metals such as pure copper[7–8], titanium alloys[9] and steel[10–11]. In contrast with the MC method, the CA method is able to quantitatively consider the effect of

deformation stored energy on growth kinetics of each recrystallized grain (R-grain) and build the relation with the actual deformation parameters. Therefore, it allows accurate predictions of the microstructural evolution and flow stress behavior under various hot working conditions.

The nucleation rate is a key factor affecting the microstructural evolution during DRX. However, it is difficult to accurately determine the nucleation rate through theoretical or experimental means, due to the complexity of DRX process and the limitation of experimental measures[12–13]. At present, the backcalculated method is mainly used to evaluate the value of nucleation rate from the measurements of the percentage of DRX and the mean size of R-grain[7]. However, in real sample, the recrystallization softening takes place concurrently with the work-hardening during DRX so that the R-grain is hardly to be accurately discriminated from deformed matrix, which leads to inaccuracy of so-determined nucleation rate. To improve the simulation performance, RANE et al[13] proposed a genetic algorithm coupled with CA method to evaluate the nucleation rate during static recrystallization (SRX).

Considering that the intrinsic information of DRX

like grain nucleation and growth is embedded in the material flow stress during hot deformation, a new method is proposed to identify the nucleation rate. In the method, the CA model, as a main part, is applied to quantitatively simulate the material microstructural evolution and the flow stress under hot working condition, and an optimization model based on adaptive response surface method (ARSM) is applied as an additional part to provide input parameters to CA model and evaluate the output of the latter. The reason to adopt an ARSM model is to reduce the computational time in optimization since CA modeling of DRX is usually a computation-intensive problem. According to the physical metallurgical principles, when the difference between the simulated stress—strain curve and the experimental data is minimized, the identified value of nucleation parameter and the microstructural evolution can reasonably reproduce the evolution in the real sample. By using the proposed method, the hot deformation behavior of an oxygen-free high-conductivity (OFHC) copper is simulated.

2 CA model of DRX

Similar to the model proposed by DING and GUO[7], three assumptions are employed:

1) The dislocation density increases with strain in both primary grains and R-grains, and DRX will occur when the dislocation density exceeds the critical value.

2) During DRX, nucleation only takes place on grain boundaries (including primary grain boundaries and R-grain boundaries).

3) The heterogeneity of grain boundary mobility is neglected.

2.1 Theoretical model of DRX

2.1.1 Modeling of dislocation evolution

The dislocation evolution model describes the effect of work hardening and dynamic recovery on dislocation density. For both primary grains and R-grains, the variation of dislocation density is calculated by the model proposed by MECKING and KOCKS[14]:

$$\frac{d\rho}{d\varepsilon} = k_1\sqrt{\rho} - k_2\rho \quad (1)$$

where k_1 and k_2 are the parameters representing work hardening and dynamic recovery, respectively.

The flow stress σ is typically calculated from the mean value of dislocation density $\bar{\rho}$ [15]:

$$\sigma = \alpha\mu b\sqrt{\bar{\rho}} \quad (2)$$

where α is a dislocation interaction term which equals 0.5–1.0 for most metals; μ is the shear modulus; and b is

the magnitude of the Burgers vector.

Substituting Eq.(1) into Eq.(2) yields:

$$\frac{d\sigma}{d\varepsilon} = \theta \left(1 - \frac{\sigma}{\sigma_s} \right) \quad (3)$$

$$\theta = \alpha\mu b k_1 / 2 \quad (4)$$

$$\sigma_s = \alpha\mu b (k_1 / k_2) \quad (5)$$

where θ is the parameter associated with the work hardening, σ_s is the saturated stress representing the balance between work hardening and dynamic recovery. According to Eqs.(3)–(5), k_1 and k_2 can be determined from experimental stress—strain data.

2.1.2 Modeling of DRX

As deformation continues, new strain-free nuclei will form on grain boundaries when the dislocation density in material exceeds a critical value. Driven by the difference of stored energy between the deformed matrix and R-grains, the newly formed R-grains will grow by expanding into their surrounding deformed matrix. The grain boundary migration rate v_i of the i th R-grain can be calculated from the grain boundary mobility m and the driving force per unit area f_i [16]:

$$v_i = m \cdot f_i \quad (6)$$

$$m = \frac{b\lambda D_{0,b}}{kT} \exp\left(-\frac{Q_b}{RT}\right) \quad (7)$$

$$f_i = \tau \cdot (\rho_{m,i} - \rho_{rex,i}) - 4\gamma_i / d_i \quad (8)$$

$$\gamma_i = \gamma_m \cdot \frac{\theta_i}{\theta_m} \left(1 - \ln \frac{\theta_i}{\theta_m} \right) \quad (9)$$

where λ is the characteristic thickness of grain boundary; $D_{0,b}$ is the boundary self-diffusion coefficient; k is the Boltzmann's constant; Q_b is the boundary diffusion activation energy; $\tau=0.5\mu b^2$, represents the dislocation line energy; $\rho_{rex,i}$ and $\rho_{m,i}$ represent the dislocation density of the i th R-grain and that of its surrounding unrecrystallized matrix, respectively; d_i is the size of R-grain; γ_i is the boundary energy; θ_i is the grain boundary misorientation; and γ_m and θ_m are the boundary energy and the misorientation for a high angle boundary, respectively.

2.2 Cellular automaton method

The CA method deals with an array of cell, the evolution of which is characterized by the state of cell that can be determined by the neighborhood and transformation rule. In order to simulate the DRX behavior of metallic material, the simulation space is discretized into an array of equally shaped quadratic cells

of 200×200 sites under the periodic boundary conditions. The size of each lattice site is $2 \mu\text{m} \times 2 \mu\text{m}$, and the simulation lattice represents $400 \mu\text{m} \times 400 \mu\text{m}$ in the real sample. Each lattice site has four state variables: 1) a dislocation density variable that describes the deformation stored energy, 2) an orientation variable, which is a random integer in the range of 1–180 and is used to evaluate the grain boundary energy, 3) a recrystallization number variable that denotes the cycles of recrystallization occurring in the area of cell and is represented by an integer in the range of 0– N , where 0 represents the unrecrystallized matrix, and 4) a grain label variable that represents different grains and is given by a positive integer in the range of 0– M .

The initial microstructure is produced by the site-saturated nucleation, i.e., a predefined number of nuclei are randomly generated at the beginning and no more nuclei are generated in the following time step. The dislocation density of each initial grain is set to the 10^{10}m^{-2} which is close to the value in annealed materials. The label of grain is initially set to 0, and added by 1 each time when new different grain emerges. With progressing deformation, the variation of dislocation density can be calculated by using Eq.(1). When the dislocation density exceeds the critical value ρ_c for nucleation of DRX, new nuclei form on grain boundaries. For two-dimensional cellular automaton, a nucleation rate I is defined, on the unit length of grain boundary where $\rho > \rho_c$, as the number of new nuclei generated per unit time. For each cell along boundary where dislocation density exceeds a critical value, its nucleation probability P_N in the time step Δt is given by

$$P_N = \frac{I \cdot \Delta t}{N_{CA}} \quad (10)$$

where $N_{CA} = 1/L_{CA}$, is the number of cells along per unit length of boundary; and L_{CA} is the cell length. For each newly formed R-grain, its initial dislocation density is again set to be 10^{10}m^{-2} . For the cell that is occupied by the R-grain, the number of recrystallization is added by 1 from its original value; at the same time, the labeling of grain is also added by 1 from its maximum value. The driving force of grain growth is provided by the difference of stored energy that exists in R-grains and their surrounding deformation matrix. For the i th R-grain, the growth velocity can be calculated from Eqs.(6)–(9) through each cell on its boundary where the boundary energy is evaluated through the maximum misorientation when the cell is surrounded by two or more differently-oriented cells. In order to simulate equiaxial grain growth, von Neumann neighborhood and a probabilistic transformation rule are utilized. Based on the studies on the scale of CA time step in the

probabilistic cellular automaton model[17–18], the transformation probability P_G can be expressed as

$$P_G = \frac{v_i \cdot \Delta t}{L_{CA}} \quad (11)$$

To ensure that both P_N and P_G are less than 1, an upper limit of Δt has to be set. The simulation tests show that there always exists $I/N_{CA} \ll 1$ in Eq.(10). Therefore, the upper limit of Δt can be defined as the ratio of the cell size L_{CA} to the maximum growth velocity v_{\max} [19]:

$$\Delta t = \frac{L_{CA}}{v_{\max}} = \frac{k_2^2 L_{CA}^2}{m\tau k_1^2} \quad (12)$$

As the deformation continues, the nucleation and grain growth can take place on grain boundaries as long as its dislocation density exceeds the critical value no matter it belongs to unrecrystallized grain or R-grain.

In the CA model, the strain increment and instantaneous strain can be obtained for a given time step Δt and strain rate. Therefore, the evolution of grain size and percentages of DRX, as well as the flow stress with strain can be obtained by simulating the nucleation and grain growth behavior at each time increment.

3 Identification of nucleation parameter

As previously mentioned, it is difficult to accurately estimate the nucleation rate due to the complexity of DRX and limitation of experiments. However, the nucleation rate is critical to the DRX behavior and the latter is a dominant factor to the material macroscopic flow stress curve. Hence, it can be expected to identify the nucleation rate by comparison of the simulated strain—stress curve and the measured one. Hereby, the identification of nucleation rate is to determine the appropriate value so that the difference between the simulated and measured flow stress curves can be minimized. In fact, it is a problem of optimization and the optimization objective can be defined as

$$f(x) = \sum_{i=1}^q \left(\frac{\sigma_i^{\text{cal}}(x) - \sigma_i^{\text{exp}}}{\sigma_i^{\text{exp}}} \right)^2 \quad (13)$$

where σ_i^{exp} and $\sigma_i^{\text{cal}}(x)$ are, respectively, measured and calculated flow stresses at the strains ε_i ($i=1, \dots, q$); q is the number of sample points on the stress—strain curve; and x is the supposed nucleation parameter I which is to be identified.

To reduce the computational cost and obtain the global optimum of nucleation rate, an adaptive response surface method (ARSM)[20–21] is applied. This idea comes from the fact that the ARSM as an approximate model can re-construct response surface model

automatically on the gradually reduced design space, so as to iteratively improve the model precision and approach to the global optimum. By taking Latin Hypercube Design (LHD) as the sampling method of nucleation rate, the flow stress is simulated by CA model at the sample points and the response surface model is constructed through least square method. The flow chart of the identification procedure which combines the CA model and ARSM-based optimization is shown in Fig.1, and the procedure is implemented as follows:

1) Predefining an initial searching range of the nucleation rate and generating the LHD sample points in this range.

2) Calculating the flow stress curve by running CA model at each sampling point, and then evaluating the simulation accuracy through Eq.(13) and storing it in the design library.

3) Constructing the response surface model by least square regression:

$$y = \beta_0 + \beta_1x + \beta_2x^2 \tag{14}$$

where y is the response; x is the boundary nucleation rate I ; and β_0, β_1 and β_2 are regression coefficients.

4) Searching for the optimum on the response surface model and evaluating the actual response at the

optimum and then storing it in the design library.

5) Reducing the searching range by defining the threshold value. Here, the threshold value, y_0 , is taken as the average value of maximum and minimum responses written in the design library, and the reduced searching range is obtained by solving the following equation:

$$\beta_2x^2 + \beta_1x + \beta_0 - y_0 = 0 \tag{15}$$

The roots, x_1 and x_2 , determine the reduced range as $[\min\{x_1, x_2\}, \max\{x_1, x_2\}]$ for subsequential searching.

6) Stopping iteration and outputting the identified nucleation rate when one of the following criterions is satisfied:

(1) The mean error of the simulated flow stress is less than 0.001, i.e., $\frac{f(x)}{q} < 0.001$.

(2) The span of the range of boundary nucleation rate I is less than 50, which means the accuracy of P_N is of the order of 10^{-5} .

7) Otherwise, updating the design library by inheriting those LHD points falling in the new reduced space for re-construction of RSM in the next iteration. Then, generating new LHD points and returning to step 2).

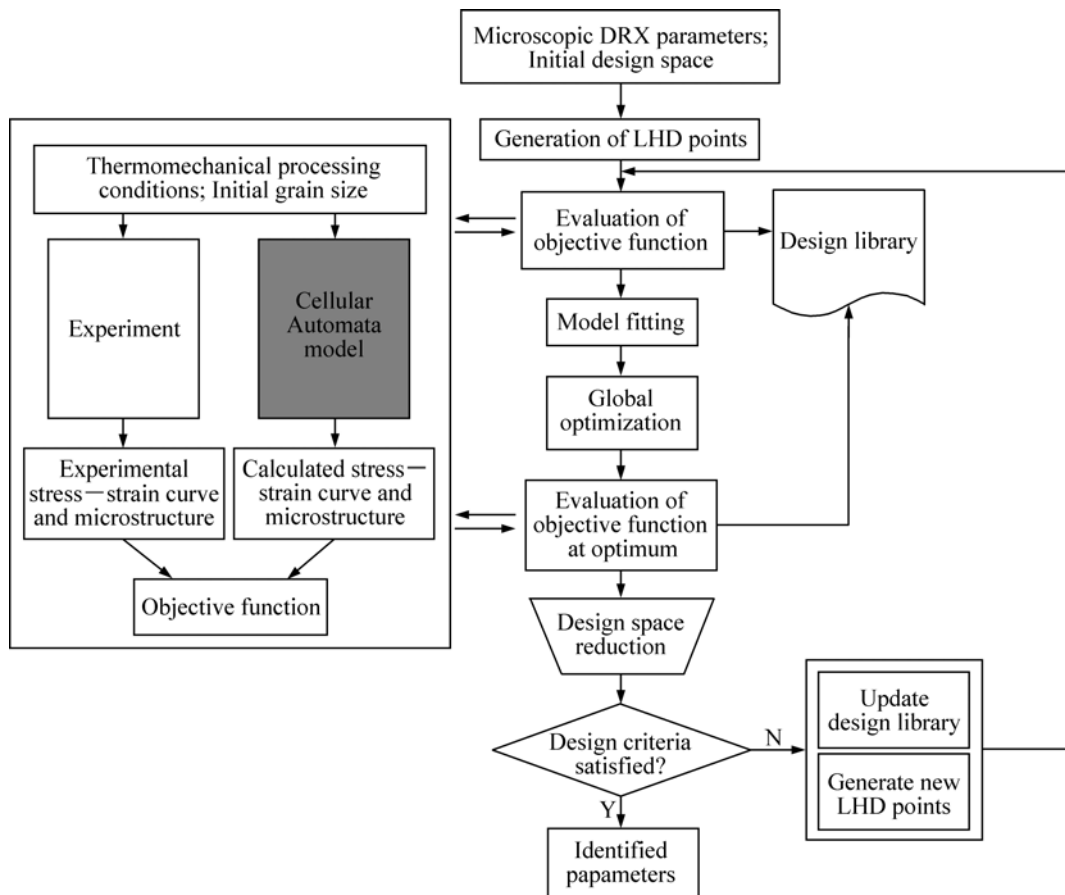


Fig.1 Flow chart of new method by coupling CA and ARSM

4 Validation and discussion

By taking an oxygen-free high-conductivity (OFHC) copper as an example, the microstructural evolution and the flow stress behavior during DRX at the temperature of 775 K and the strain rate of 0.002 s^{-1} is simulated, and the experimental data under the same deformation condition are obtained from Ref.[22]. The values of material constants for the simulation are listed in Table 1. The values of k_1 and k_2 are determined through least square method by using the experimental stress—strain data prior to the initiation of DRX. From the plot of $d\sigma/d\varepsilon$ versus σ shown in Fig.2, the approximate values of θ and σ_s can be obtained by linear regression method (Eq.(3)). Then, from Eqs.(4) and (5), the values of k_1 and k_2 are 3.94×10^8 and 20.904, respectively. For the boundary nucleation rate I , the initial range is designated as [5, 5 000]. Since there are three unknown coefficients in the response surface model (Eq.(14)), the number of LHD sampling points must be larger than or equal to 3 and it is taken as 6 in this work. After six times of re-construction of response surface model, the identified value of I is 655. The simulated results are compared with the experimental measurements.

Table 1 Values of material parameters used in simulations[7]

$Q_b/(\text{kJ}\cdot\text{mol}^{-1})$	$\lambda D_{0,b}/(\text{m}^3\cdot\text{s}^{-1})$	b/m	μ/Pa	$\gamma_m/(\text{J}\cdot\text{m}^{-2})$
104	5.0×10^{-15}	2.56×10^{-10}	4.21×10^{10}	0.625

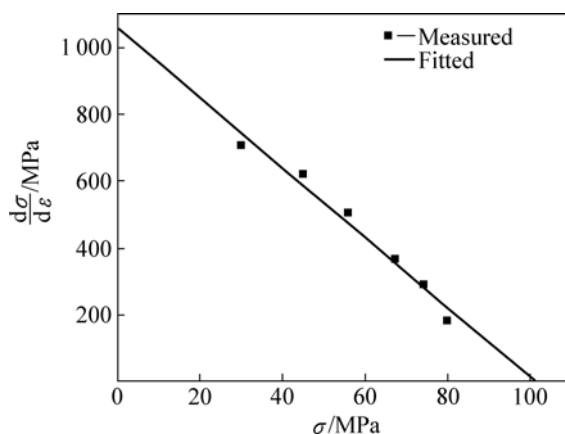


Fig.2 Curve of $d\sigma/d\varepsilon$ — σ of OFHC copper to determine θ and σ_s

In Fig.3, the simulated stress—strain curve is compared with the measured one. The simulated flow stress is calculated from the mean value of dislocation density on the simulation lattice at each time step (Eq.(2)). The average relative error of the simulated flow stress curve is about 3.62%, which is less than that in Ref.[7]; while in the latter work, the nucleation rate is obtained from the experimentally backcalculated method.

This indicates that the simulation precision is improved by the proposed method. The reason for the deviation may be attributed to such factors as the model assumptions, the grain deformation, the intragranular nucleation and the heterogeneously distributed dislocation density, which influence the DRX process in practice. Here, they are not considered in the simulation in order to compare the results simulated by the proposed method with those obtained in Ref.[7] under the similar simulation condition.

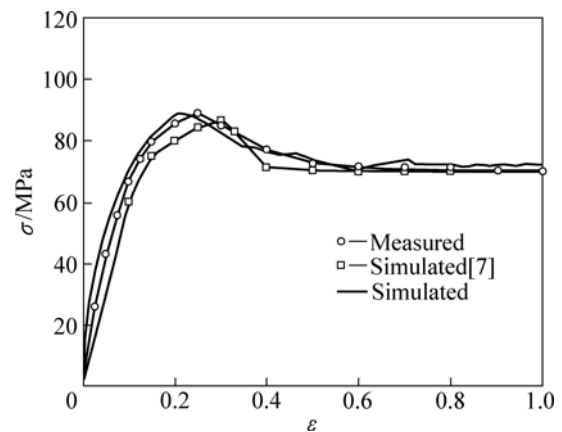


Fig.3 Comparison of simulated and measured stress—strain curves of OFHC copper

Fig.4 shows the simulated microstructure at different strains, where white areas represent the primary grains and other areas represent the R-grains. The mean grain size of simulated initial microstructure is $81 \mu\text{m}$, which is close to the measured one of $78 \mu\text{m}$. As usually observed in experiment, R-grains form randomly along primary boundaries and the microstructure is characterized by necklace morphology at the onset of DRX. With progressing deformation, the primary grains are gradually consumed and covered by R-grains.

The evolution of the average grain size with strain is shown in Fig.5. When the strain reaches the critical value, DRX occurs so that the average grain size d_{avg} reduces rapidly. As the strain increases, the dropping rate of d_{avg} reduces gradually. When strain is about 0.6, the mean grain size approaches its steady value of $11.8 \mu\text{m}$, which is close to the measured value of $14 \mu\text{m}$ [22].

Fig.6 compares the simulated percentage of DRX with measured one, where the simulated percentage of DRX is calculated by the ratio of the number of recrystallized cells to the total number of cells. It can be seen that the DRX occurs when the strain exceeds its critical value and the simulated curve has a characteristic sigmoidal shape. It can also be seen that the percentage of DRX simulated by the proposed method shows better agreement with the experiments compared with the simulated one in Ref.[7].

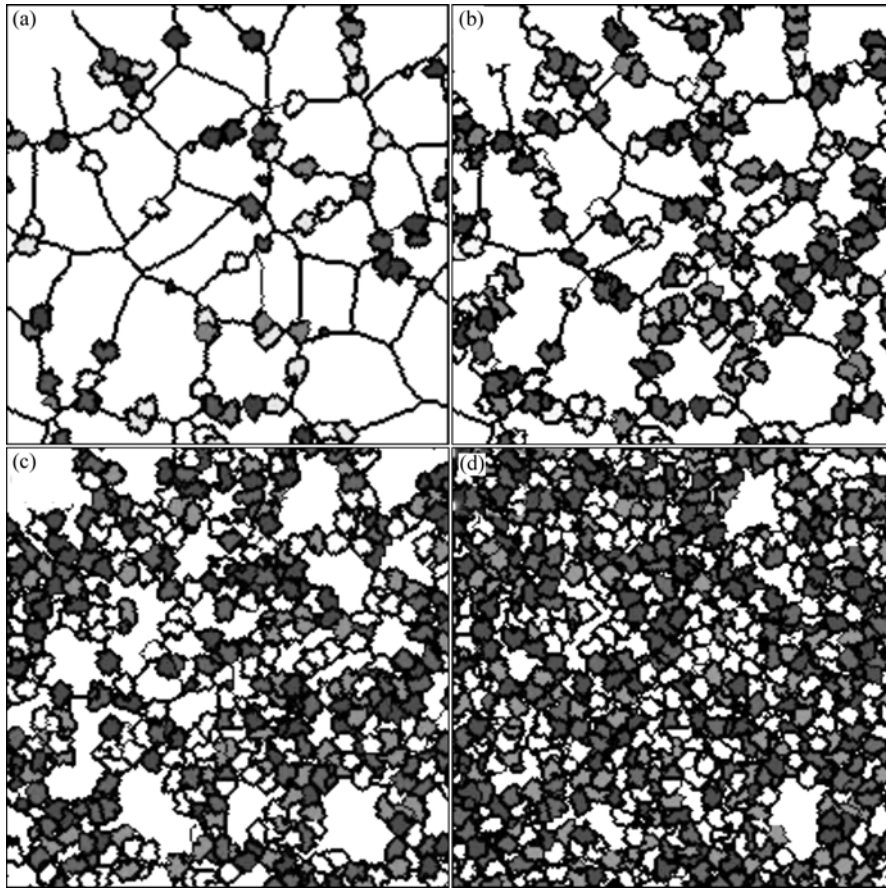


Fig.4 Simulated microstructural evolution of OFHC copper at different strains: (a) 0.25; (b) 0.35; (c) 0.45; (d) 0.55

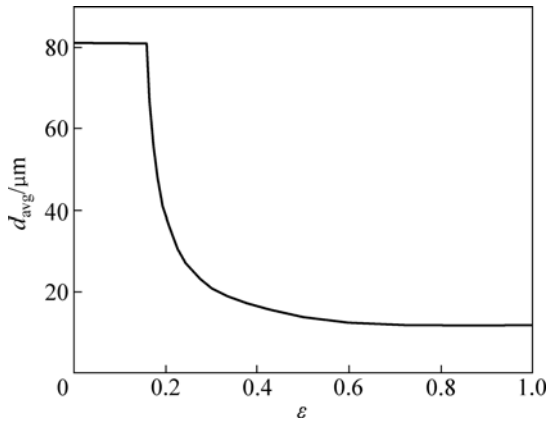


Fig.5 Dependence of average grain size on strain of OFHC copper

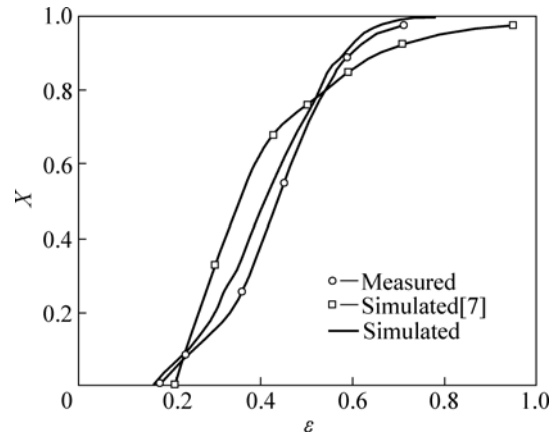


Fig.6 Comparison of simulated percentage of DRX and measured one for OFHC copper

It is noted that the boundary nucleation rate in the CA model is defined on the grain boundary where $\rho > \rho_c$. However, the length of the boundary where $\rho > \rho_c$ varies with strain due to the nucleation and grain growth during DRX. Therefore, the boundary nucleation rate cannot efficiently represent the number of new grains formed per unit time on the simulation lattice. Here, a volume nucleation rate, \dot{n}_v , is defined to represent the number of nuclei formed per unit time and unit volume. According to the stereological principium, an 2D area nucleation

rate, \dot{n}_s , obtained from CA model can be used to equivalently represent the 3D volume nucleation rate, and its value can reasonably reflect the softening effect of recrystallization. Fig.7 shows the strain dependence of \dot{n}_s , from which an irregular fluctuation is exhibited. The reason of the fluctuation is that the nucleation takes place randomly and the length of the boundary where $\rho > \rho_c$ changes with strain nonlinearly. Besides that, \dot{n}_s increases with strain in the initial stage and gradually

reaches a steady mean value with oscillation in a certain range. This tendency is closely related to the variation of mean grain size which directly affects the evolution of boundary length with $\rho > \rho_c$. These characteristics of \dot{n}_s as a function of strain are consistent with the theoretical analysis[23] and the results simulated by the Monte Carlo method[4–5]. The above analysis indicates that the flow stress-based nucleation rate identification method can improve the simulation accuracy of both microstructural evolution and flow stress behavior. And vice versa, the identified nucleation rate is also reasonable.

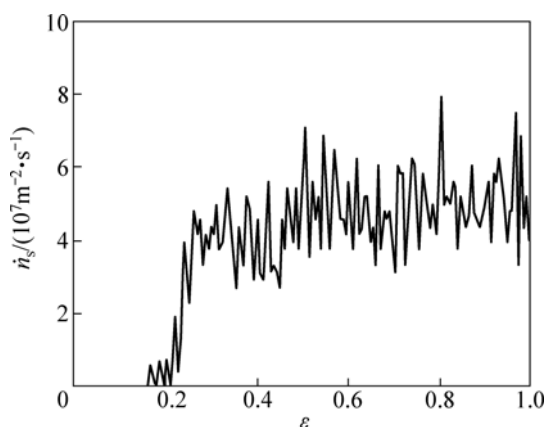


Fig.7 Dependence of area nucleation rate on strain of OFHC copper

5 Conclusions

1) To overcome the difficulties in determining the nucleation rate, a flow stress-based nucleation rate identification method is proposed, in which the CA model is incorporated with an adaptive response surface model to search for the reasonable nucleation rate. This method provides an alternative strategy for reasonable determination of nucleation rate.

2) The microstructural evolution and the flow stress behavior of oxygen-free high-conductivity copper under hot deformation conditions is simulated with the proposed method. The simulated results agree well with the experimental observations, indicating that the new method can effectively determine the nucleation rate and improves the simulation accuracy of microstructural evolution.

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(Edited by YANG Bing)